EE 247B/ME 218: Introduction to MEMS Design

Module 17: Noise & MDS



EE C247B - ME C218 Introduction to MEMS Design Fall 2018

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Module 17: Noise & MDS

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Lecture Outline

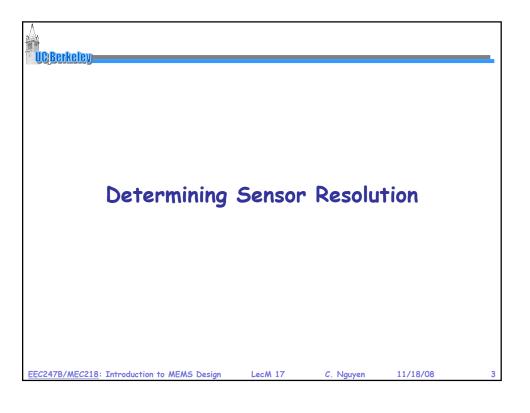
- * Reading: Senturia Chpt. 16
- Lecture Topics:
 - Minimum Detectable Signal
 - ♥ Noise
 - Circuit Noise Calculations
 - ◆ Noise Sources
 - Equivalent Input-Referred Noise
 - ⇔ Gyro MDS
 - **←** Equivalent Noise Circuit
 - **★** Example ARW Determination

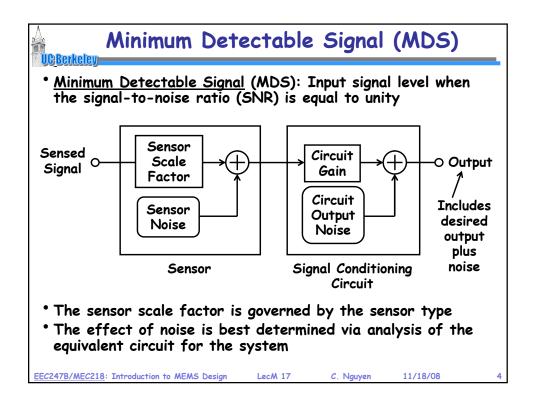
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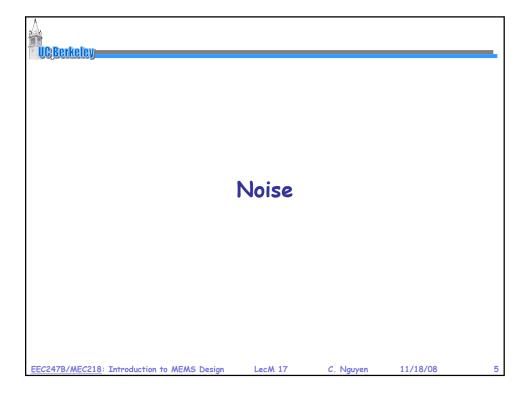
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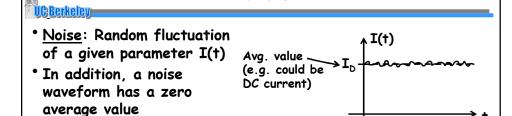
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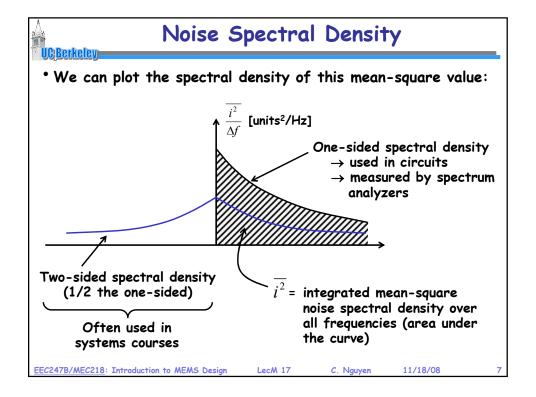
Noise

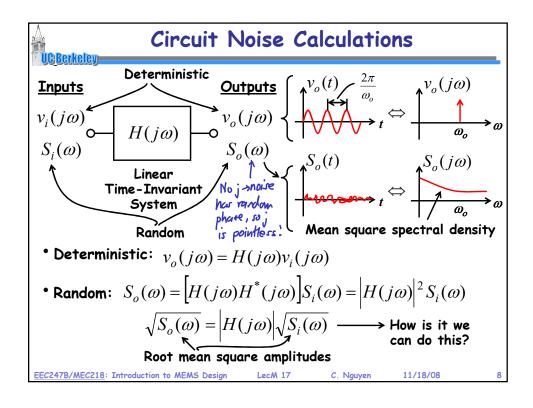
- * We can't handle noise at instantaneous times
- But we can handle some of the averaged effects of random fluctuations by giving noise a power spectral density representation
- Thus, represent noise by its mean-square value:

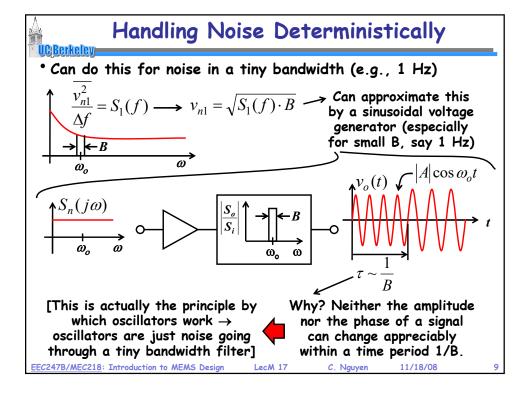
Let
$$i(t) = I(t) - I_D$$

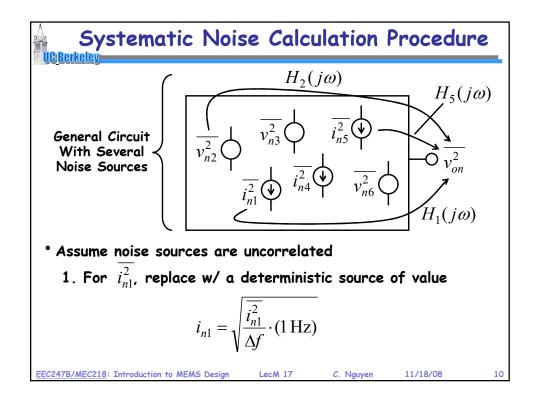
Then
$$\overline{i^2} = \overline{\left(I - I_D\right)^2} = \lim_{T \to \infty} \frac{1}{T} \int_0^T \left|I - I_D\right|^2 dt$$

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Systematic Noise Calculation Procedure

- 2. Calculate $v_{on1}(\omega)$ = $i_{n1}(\omega)H(j\omega)$ (treating it like a deterministic signal)
- 3. Determine $\overline{v_{on1}^2} = \overline{i_{n1}^2} \cdot \left| H(j\omega) \right|^2$ 4. Repeat for each noise source: $\overline{i_{n1}^2}$, $\overline{v_{n2}^2}$, $\overline{v_{n3}^2}$
- 5. Add noise power (mean square values)

$$\overline{v_{onTOT}^2} = \overline{v_{on1}^2 + v_{on2}^2 + v_{on3}^2 + v_{on4}^2 + \cdots}$$

$$v_{onTOT} = \sqrt{\overline{v_{on1}^2 + \overline{v_{on2}^2 + v_{on3}^2 + \overline{v_{on4}^2 + \cdots}}}$$

Total rms value

Noise Sources

Thermal Noise

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- Thermal Noise in Electronics: (Johnson noise, Nyquist noise)
 - Produced as a result of the thermally excited random motion of free e⁻'s in a conducting medium
 - ♥ Path of e-'s randomly oriented due to collisions
- * Thermal Noise in Mechanics: (Brownian motion noise)
 - Thermal noise is associated with all dissipative processes that couple to the thermal domain
 - Any damping generates thermal noise, including gas damping, internal losses, etc.
- Properties:
 - ♦ Thermal noise is white (i.e., constant w/ frequency)
 - Proportional to temperature
 - Not associated with current
 - \$ Present in any real physical resistor

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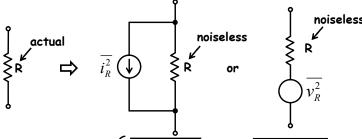
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Circuit Representation of Thermal Noise

* Thermal Noise can be shown to be represented by a series voltage generator $\overline{v_R^2}$ or a shunt current generator $\overline{i_R^2}$



Note: These are one-sided mean-square spectral densities! To make them 2-sided, must divide by 2.

 $\frac{\overline{i_R^2}}{\Delta f} = \frac{4kT}{R}$

 $\frac{\overline{v_R^2}}{\Delta f} = 4kTR$

where $4kT = 1.66x10^{-20}V \cdot C$ and where these are spectral densities.

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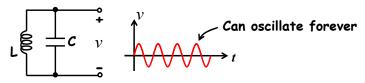
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Noise in Capacitors and Inductors?

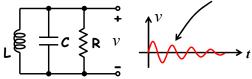
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- Resistors generate thermal noise
- Capacitors and inductors are noiseless → why?



• Now, add a resistor:

Decays to zero



But this violates the laws of thermodynamics, which require that things be in constant motion at finite temperature

Need to add a forcing function, like a noise voltage v_R^2 to keep the motion going \rightarrow and this noise source is associated with R

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Why 4kTR?

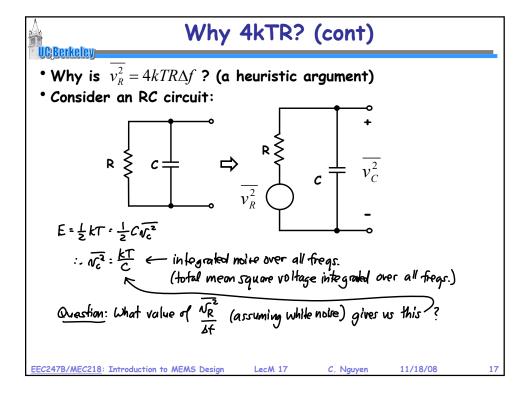
- Why is $v_R^2 = 4kTR\Delta f$ (a heuristic argument)
- The <u>Equipartition Theorem of Statistical Thermodynamics</u> says that there is a mean energy (1/2)kT associated w/ each degree of freedom in a given system
- An electronic circuit possesses two degrees of freedom: ♥ Current, i, and voltage, v

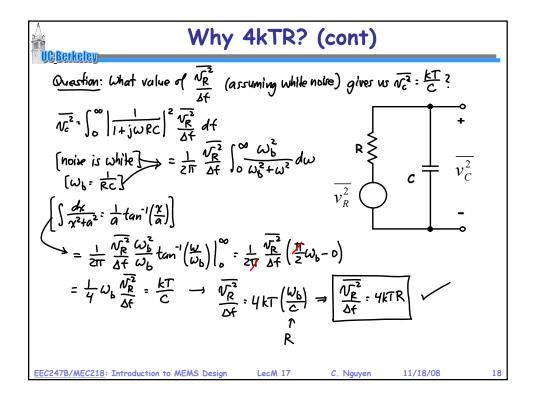
♦ Thus, we can write:

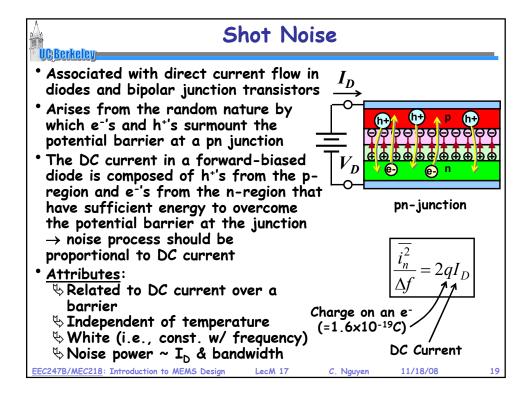
can write:
$$\frac{1}{2}Li^{2} = \frac{1}{2}k_{B}T$$
, $\frac{1}{2}Cv^{2} = \frac{1}{2}k_{B}T$

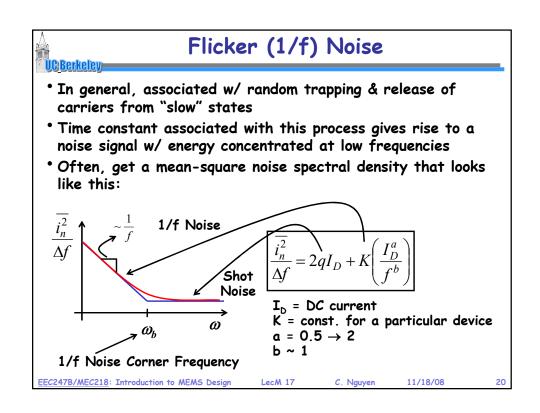
 Similar expressions can be written for mechanical systems ♦ For example: for displacement, x

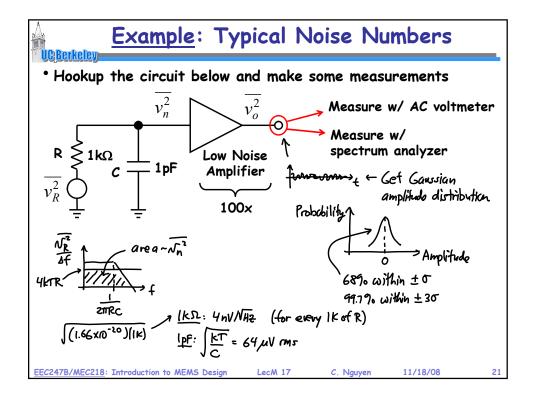
Spring constant $\frac{1}{2}k\overline{x^2} = \frac{1}{2}k_BT$

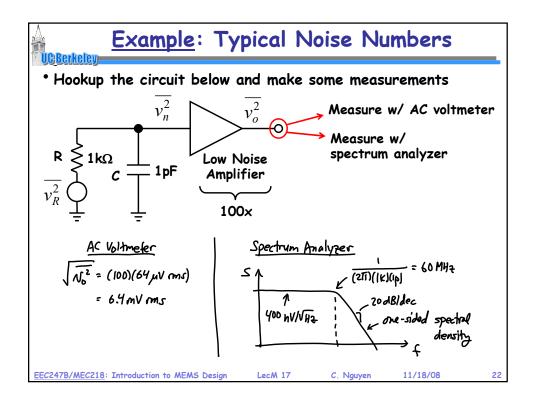


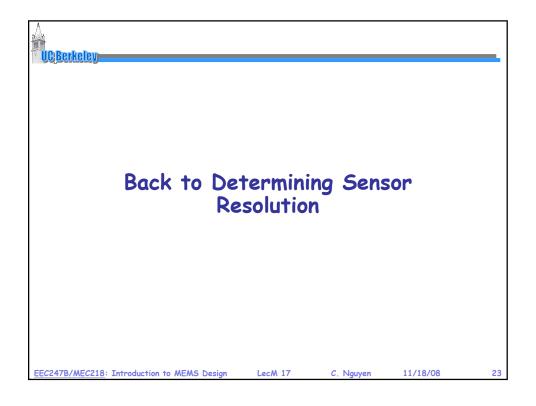


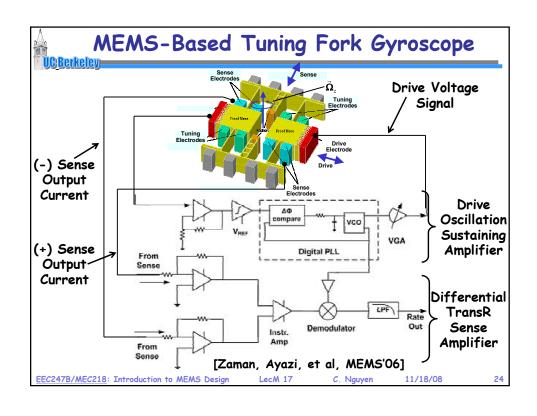


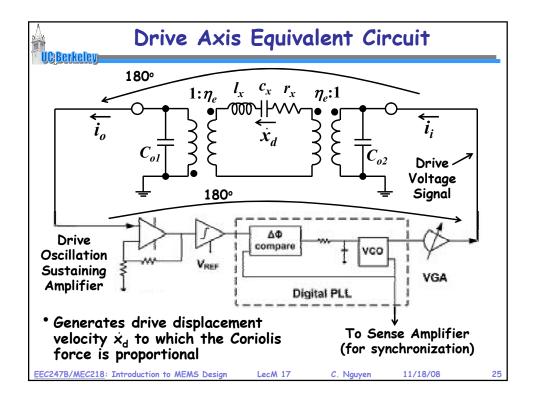


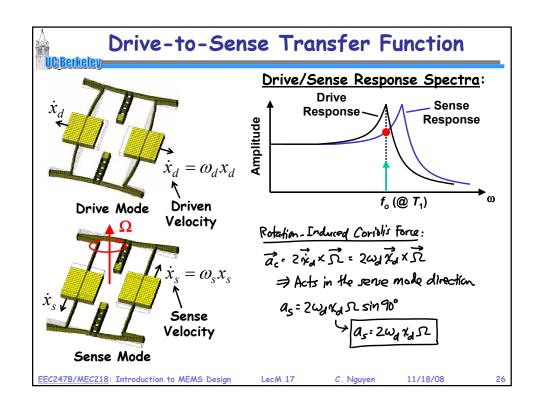


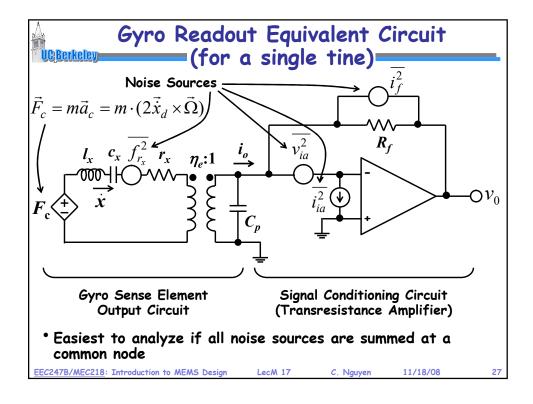


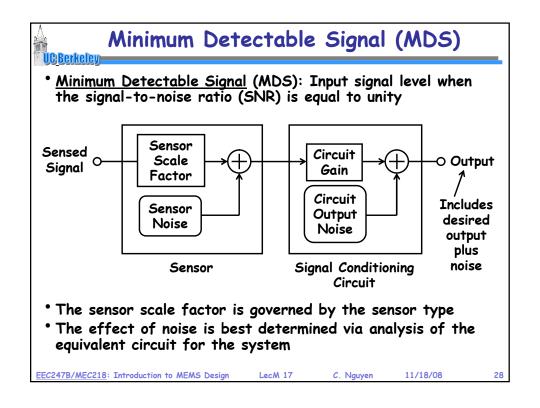




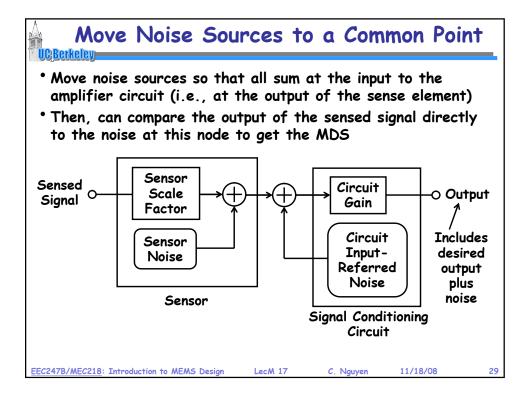


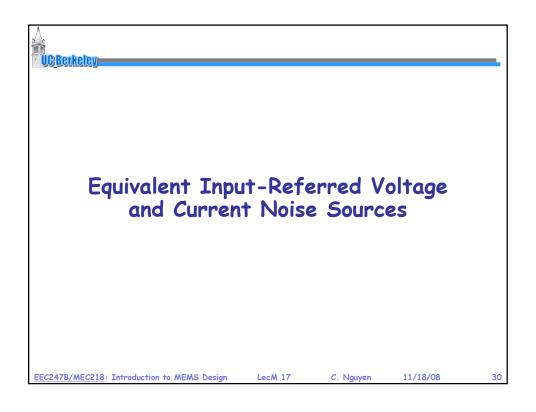






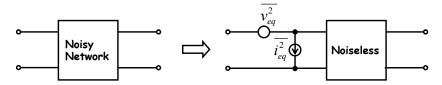
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Equivalent Input v, i Noise Generators

• Take a noisy 2-port network and represent it by a noiseless network with input ν and i noise generators that generate the same total output noise



- Remarks:
 - 1. Works for linear time-invariant networks
 - 2. v_{eq} and i_{eq} are generally correlated (since they are derived from the same sources)
 - 3. In many practical circuits, one of $v_{\rm eq}$ and $i_{\rm eq}$ dominates, which removes the need to address correlation
 - 4. If correlation is important \rightarrow easier to return to original network with internal noise sources

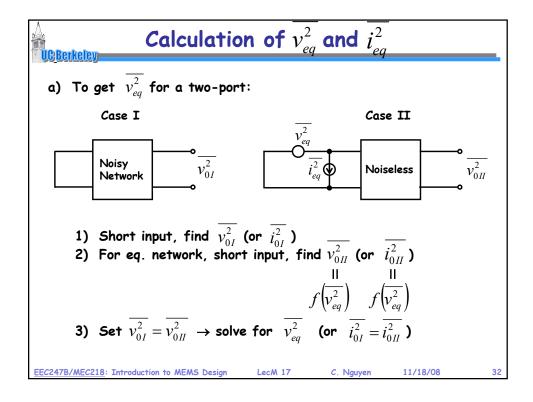
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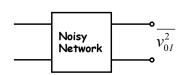
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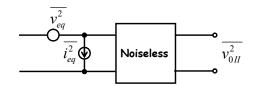
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b) To get $\overline{i_{eq}^2}$ for a 2-port:





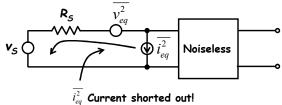
- 1) Open input, find $\overline{v_{0I}^2}$ (or $\overline{i_{0I}^2}$)
- 2) Open input for eq. circuit, find $\overline{v_{0II}^2}$ (or $\overline{i_{0II}^2}$)

 3) Set $\overline{v_{0I}^2} = \overline{v_{0II}^2} \left(\overline{i_{eq}^2}\right) \rightarrow \text{solve for } \overline{i_{eq}^2} \left(\text{or } \overline{i_{0I}^2} = \overline{i_{0II}^2} \left(\overline{i_{eq}^2}\right)\right)$
- * Once the equivalent input-referred noise generators are found, noise calculations become straightforward as long as the noise generators can be treated as uncorrelated

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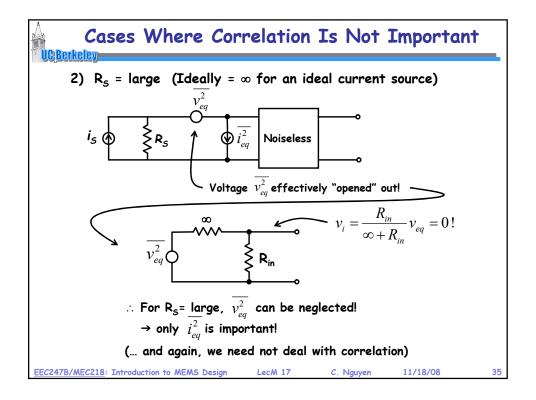
Cases Where Correlation Is Not Important

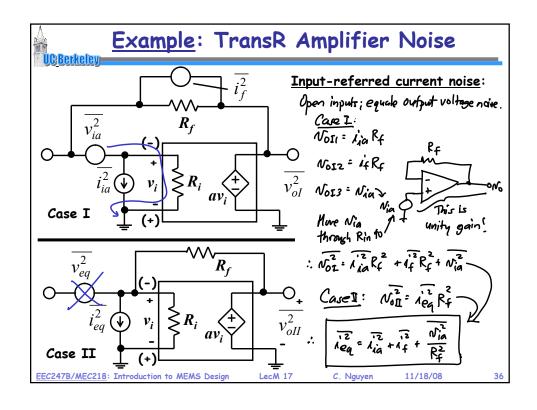
- There are two common cases where correlation can be ignored:
 - 1. Source resistance R_s is small compared to input resistance $R_i \rightarrow i.e.$, voltage source input
 - 2. Source resistance R_s is large compared to input resistance $R_i \rightarrow i.e.$, current source input
 - 1) R_s = small (ideally = 0 for an ideal voltage source):

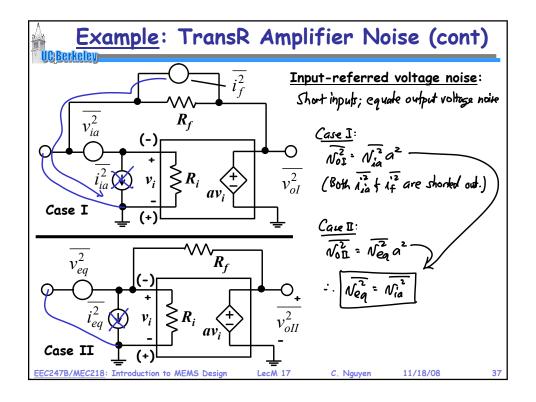


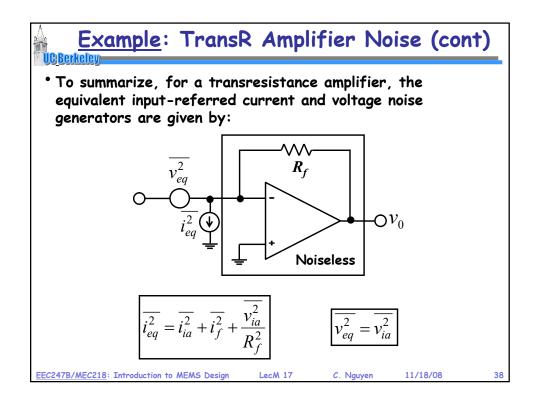
 \therefore For R_s= small, $\overline{i_{eq}^2}$ can be neglected \Rightarrow only $\overline{v_{eq}^2}$ is important! (Thus, we need not deal with correlation)

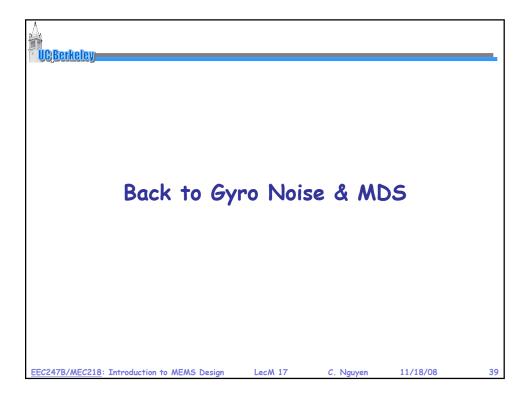
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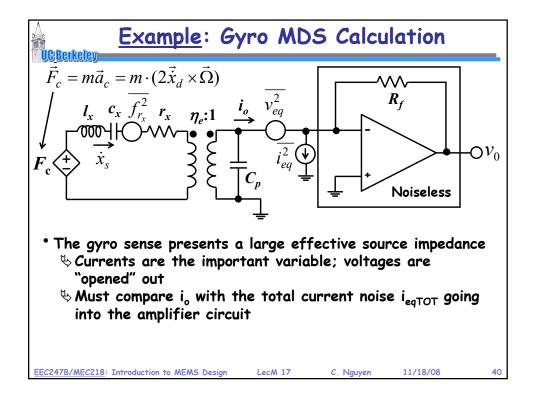


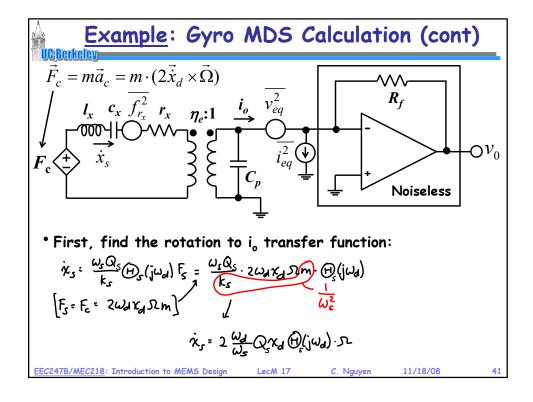


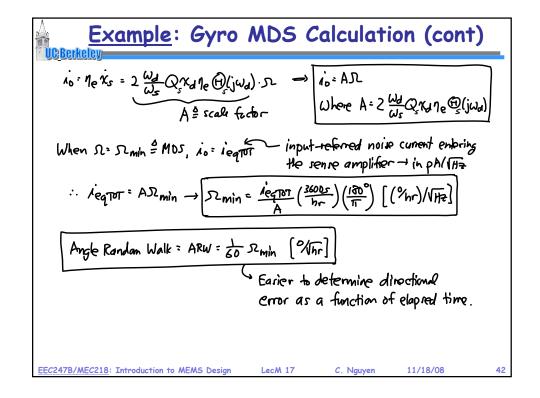


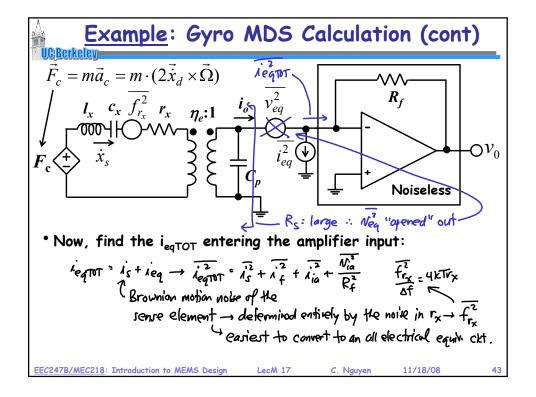


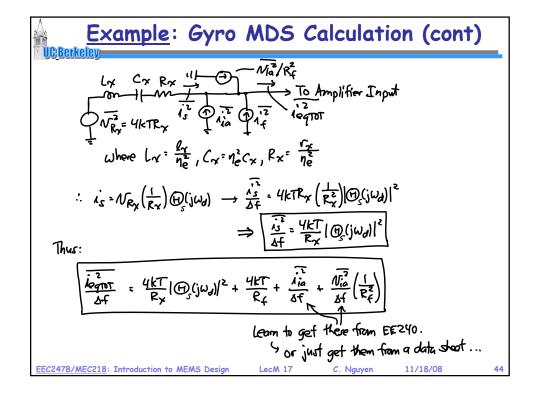


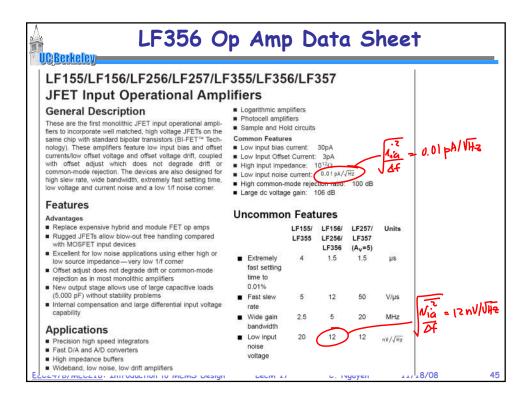


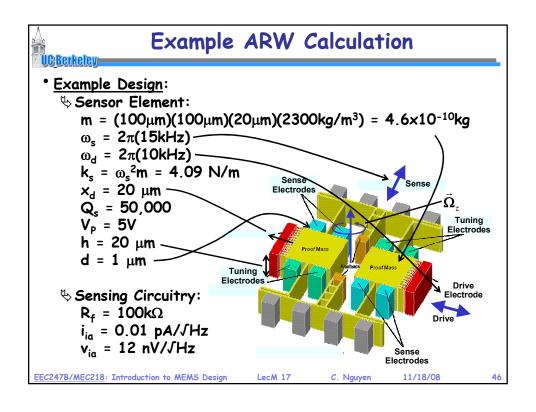












Example ARW Calculation (cont)

Get notation rate to output current scale factor:

$$A = 2 \frac{\omega_d}{\omega_s} Q_s \kappa_d \eta_e \left(\frac{|Q|}{|Q|} (|\omega_d|)\right) = 2 \frac{|Q|}{|S|} (sok) (sok) (sole) (sole o) (0.000024) = 2.83 \times 10^{-12} C$$

$$\left(\frac{|Q|}{|Q|} (|\omega_s| |\omega_s|)\right) = 2 \frac{|Q|}{|S|} (sok) (sok) (sole o) (0.000024) = 2.83 \times 10^{-12} C$$

$$\left(\frac{|Q|}{|Q|} (|\omega_s| |\omega_s|)\right) = 2 \frac{|Q|}{|Q|} (|S|) (|$$

What if
$$\omega_{d} = \omega_{s}$$
?

If $\omega_{d} = \omega_{s} = 15KH^{2}$, then $|\Theta_{c}|_{S} |\omega_{d}| = 1$ and

$$A = 2 \frac{|\omega_{d}|_{S} |\nabla_{x_{d}} |\nabla_{y_{d}} |\Theta_{c}|_{S} |\omega_{d}|}{|\omega_{s}|_{S} |\nabla_{s}|_{S} |\nabla_{$$